

MOSFET – N-Channel, POWERTRENCH®

80 V, 220 A, 3.0 mΩ

FDBL86366-F085

Features

- Typical $R_{DS(on)}$ = 2.4 mΩ at V_{GS} = 10 V, I_D = 80 A
- Typical $Q_{g(tot)}$ = 86 nC at V_{GS} = 10 V, I_D = 80 A
- UIS Capability
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

Applications

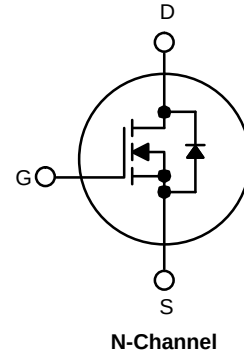
- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Integrated Starter/Alternator
- Primary Switch for 12 V Systems

MOSFET MAXIMUM RATINGS (T_J = 25 °C unless otherwise noted)

Symbol	Parameter	Ratings	Unit
V_{DSS}	Drain-to-Source Voltage	80	V
V_{GS}	Gate-to-Source Voltage	±20	V
I_D	Drain Current – Continuous (V_{GS} = 10), T_C = 25 °C (Note 1)	220	A
	Pulsed Drain Current, T_C = 25 °C	See Figure 4	
E_{AS}	Single Pulse Avalanche Energy (Note 2)	205	mJ
P_D	Power Dissipation	300	W
	Derate Above 25 °C	2.0	W/°C
T_J, T_{STG}	Operating and Storage Temperature	–55 to +175	°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	0.5	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient (Note 3)	43	°C/W

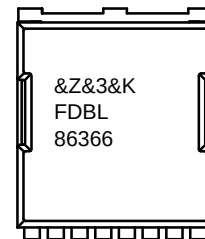
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Current is limited by silicon.
2. Starting T_J = 25 °C, L = 0.1 mH, I_{AS} = 64 A, V_{DD} = 80 V during inductor charging and V_{DD} = 0 V during time in avalanche.
3. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design, while $R_{\theta JA}$ is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.



H-PSOF8L
CASE 100CU

MARKING DIAGRAM



&Z = Assembly Plant Code
&3 = Numeric Date Code
&K = Lot Code
FDBL86366 = Specific Device Code

ORDERING INFORMATION

Device	Top Mark	Package	Shipping†
FDBL86366 -F085	FDBL86366	H-PSOF8L	2000 Units/ Tape&Reel

* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, [SOLDERRM/D](#).

ELECTRICAL CHARACTERISTICS ($T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
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OFF CHARACTERISTICS

BV_{DSS}	Drain-to-Source Breakdown Voltage	$I_D = 250\text{ }\mu\text{A}$, $V_{GS} = 0\text{ V}$	80	–	–	V
I_{DSS}	Drain-to-Source Leakage Current	$V_{DS} = 80\text{ V}$, $V_{GS} = 0\text{ V}$	$T_J = 25\text{ }^{\circ}\text{C}$	–	–	μA
			$T_J = 175\text{ }^{\circ}\text{C}$ (Note 4)	–	–	mA
I_{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 20\text{ V}$	–	–	± 100	nA

ON CHARACTERISTICS

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 250\text{ }\mu\text{A}$	2.0	3.0	4.0	V
$R_{DS(on)}$	Drain to Source on Resistance	$I_D = 80\text{ A}$, $V_{GS} = 10\text{ V}$	$T_J = 25\text{ }^{\circ}\text{C}$	–	2.4	$\text{m}\Omega$
			$T_J = 175\text{ }^{\circ}\text{C}$ (Note 4)	–	4.9	$\text{m}\Omega$

DYNAMIC CHARACTERISTICS

C_{iss}	Input Capacitance	$V_{DS} = 40\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 1\text{ MHz}$		–	6320	–	pF
C_{oss}	Output Capacitance			–	1030	–	pF
C_{rss}	Reverse Transfer Capacitance			–	32	–	pF
R_g	Gate Resistance	$f = 1\text{ MHz}$		–	2.1	–	Ω
$Q_{g(ToT)}$	Total Gate Charge at 10 V	$V_{GS} = 0\text{ to }10\text{ V}$	$V_{DD} = 64\text{ V}$, $I_D = 80\text{ A}$	–	86	112	nC
$Q_{g(th)}$	Threshold Gate Charge	$V_{GS} = 0\text{ to }2\text{ V}$		–	12	18	nC
Q_{gs}	Gate-to-Source Gate Charge	$V_{DD} = 64\text{ V}$, $I_D = 80\text{ A}$		–	30	–	nC
Q_{gd}	Gate-to-Drain “Miller” Charge			–	18	–	nC

SWITCHING CHARACTERISTICS

t_{on}	Turn-On Time	$V_{DD} = 40\text{ V}$, $I_D = 80\text{ A}$, $V_{GS} = 10\text{ V}$, $R_{GEN} = 6\text{ }\Omega$		–	–	98	ns
$t_{d(on)}$	Turn-On Delay			–	30	–	ns
t_r	Rise Time			–	34	–	ns
$t_{d(off)}$	Turn-Off Delay			–	40	–	ns
t_f	Fall Time			–	17	–	ns
t_{off}	Turn-Off Time			–	–	86	ns

DRAIN-SOURCE DIODE CHARACTERISTIC

V_{SD}	Source-to-Drain Diode Voltage	$I_{SD} = 80\text{ A}$, $V_{GS} = 0\text{ V}$	–	–	1.25	V
		$I_{SD} = 40\text{ A}$, $V_{GS} = 0\text{ V}$	–	–	1.2	V
t_{rr}	Reverse-Recovery Time	$I_F = 80\text{ A}$, $dI_{SD}/dt = 100\text{ A}/\mu\text{s}$, $V_{DD} = 64\text{ V}$	–	80	120	ns
Q_{rr}	Reverse-Recovery Charge		–	95	140	nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. The maximum value is specified by design at $T_J = 175\text{ }^{\circ}\text{C}$. Product is not tested to this condition in production.



TYPICAL CHARACTERISTICS

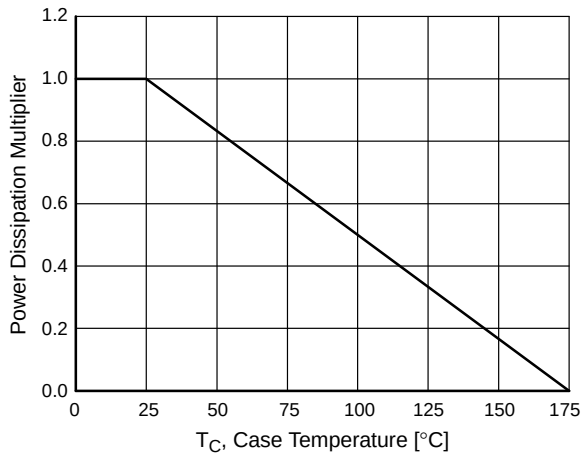


Figure 1. Normalized Power Dissipation vs. Case Temperature

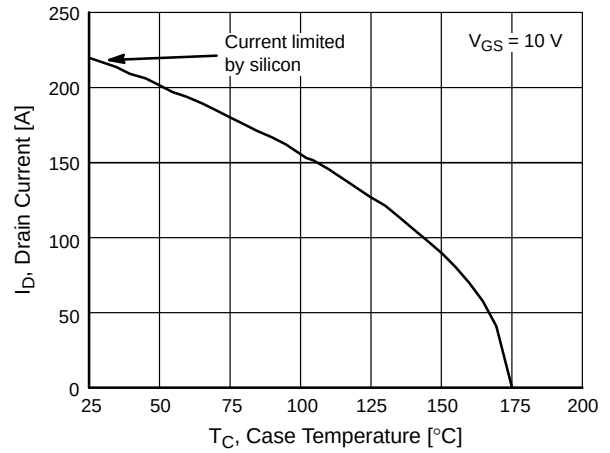


Figure 2. Maximum Continuous Drain Current vs. Case Temperature

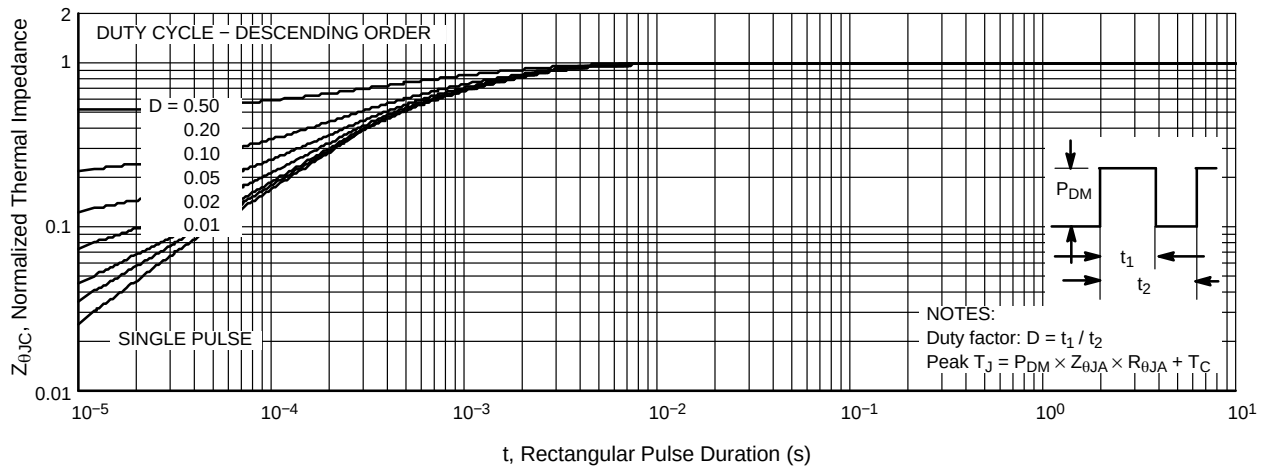


Figure 3. Normalized Maximum Transient Thermal Impedance

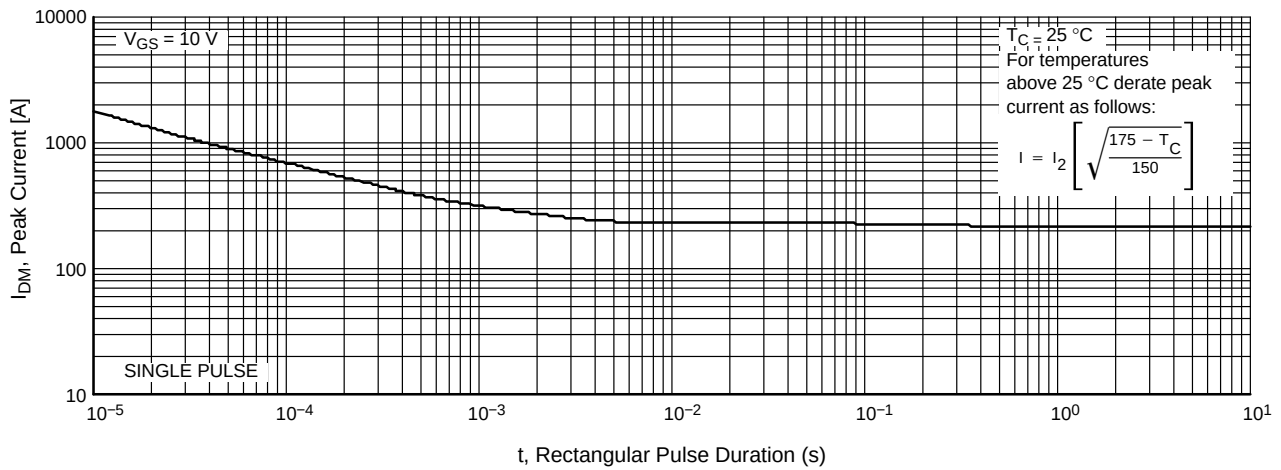


Figure 4. Peak Current Capability

TYPICAL CHARACTERISTICS (CONTINUED)

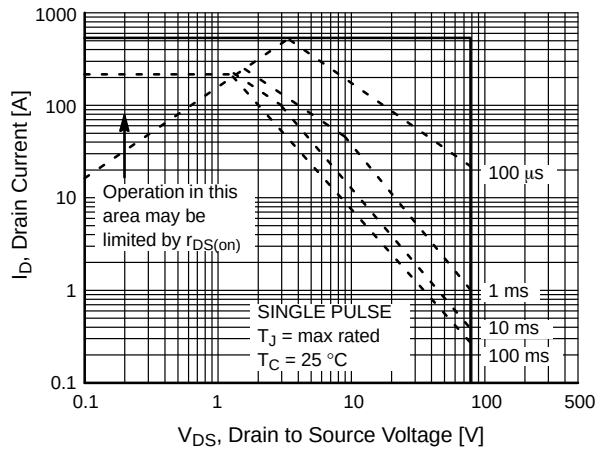


Figure 5. Forward Bias Safe Operating Area

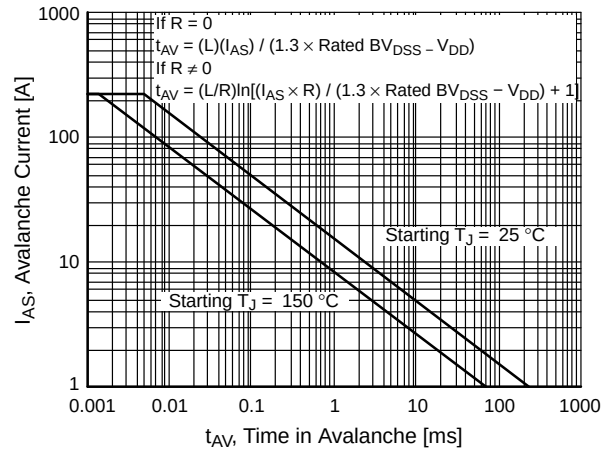
NOTE: Refer to onsemi Application Notes [AN7514](#) and [AN7515](#).

Figure 6. Unclamped Inductive Switching Capability

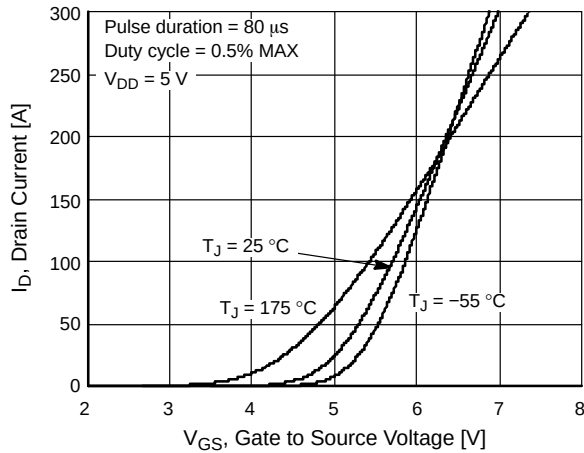


Figure 7. Transfer Characteristics

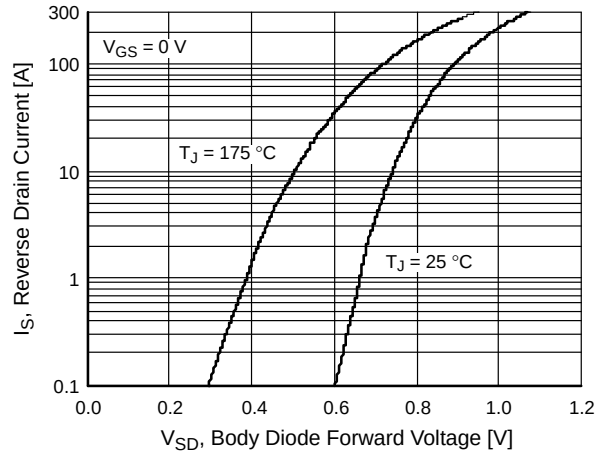


Figure 8. Forward Diode Characteristics

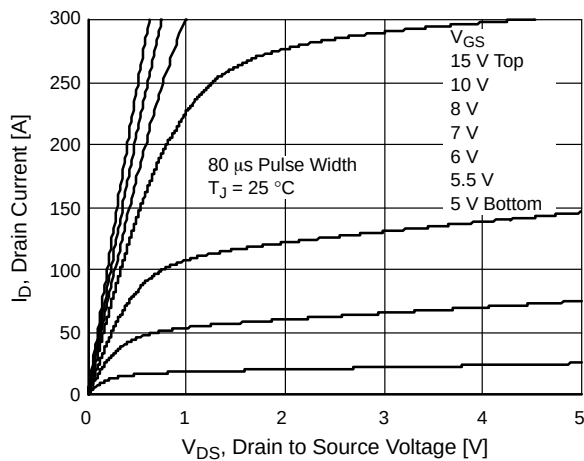


Figure 9. Saturation Characteristics

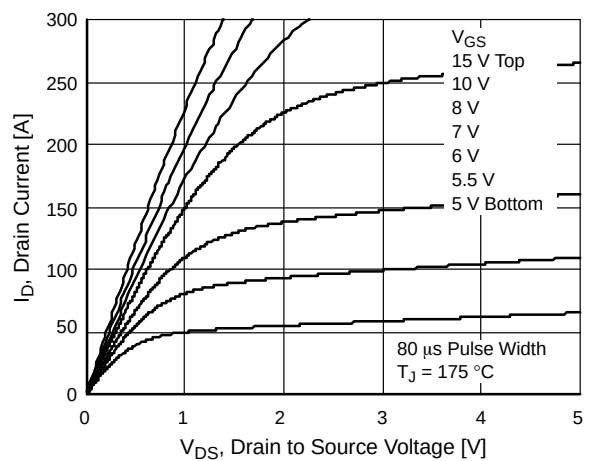


Figure 10. Saturation Characteristics

TYPICAL CHARACTERISTICS (CONTINUED)

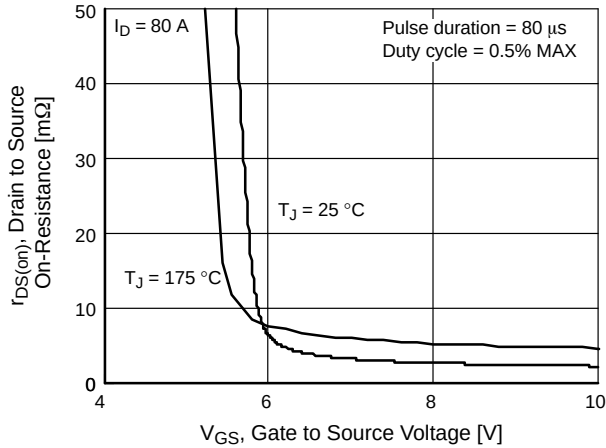
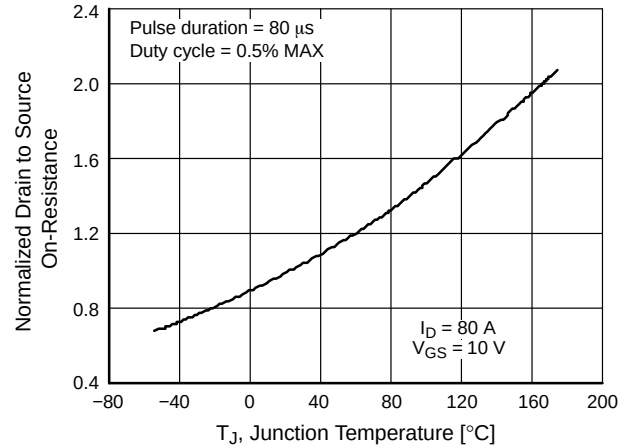
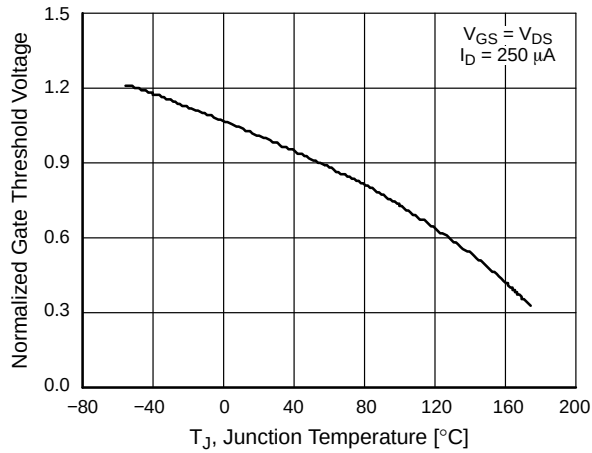
Figure 11. $R_{DS(on)}$ vs. Gate VoltageFigure 12. Normalized $R_{DS(on)}$ vs. Junction Temperature

Figure 13. Normalized Gate Threshold Voltage vs. Temperature

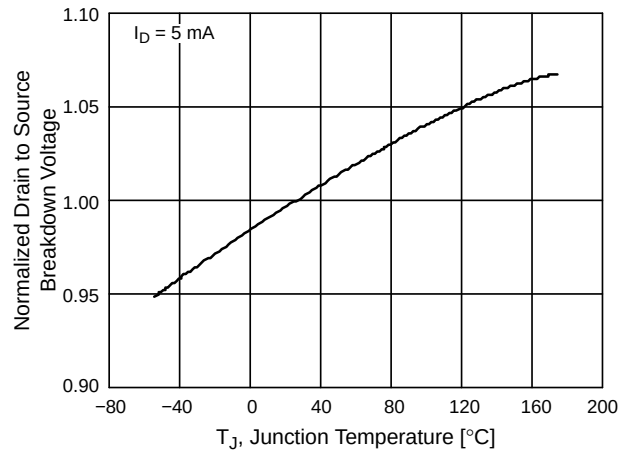


Figure 14. Normalized Drain to Source Breakdown Voltage vs. Junction Temperature

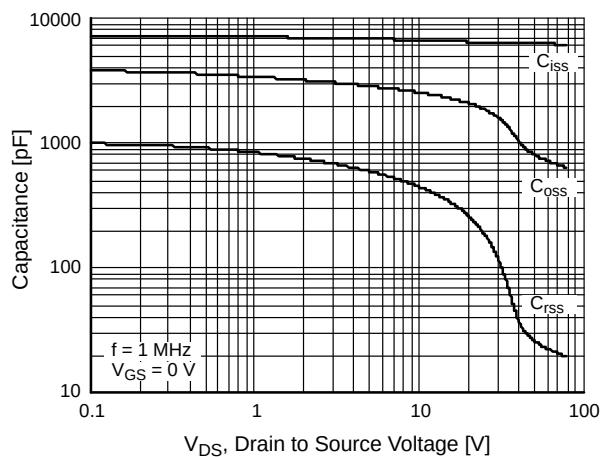


Figure 15. Capacitance vs. Drain to Source Voltage

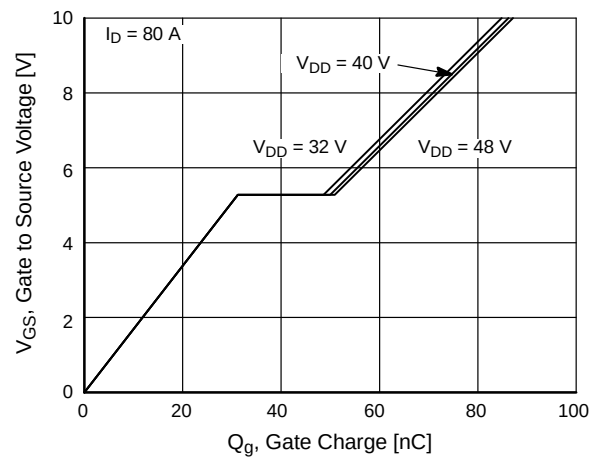


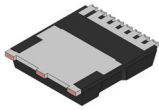
Figure 16. Gate Charge vs. Gate to Source Voltage

REVISION HISTORY

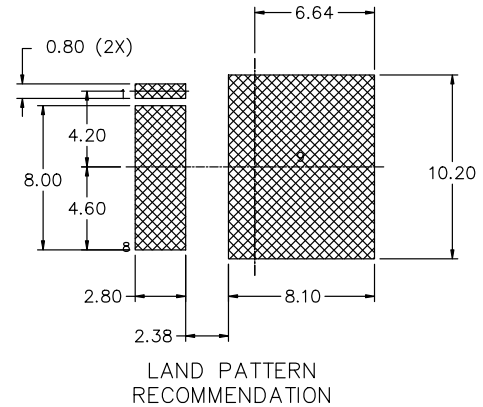
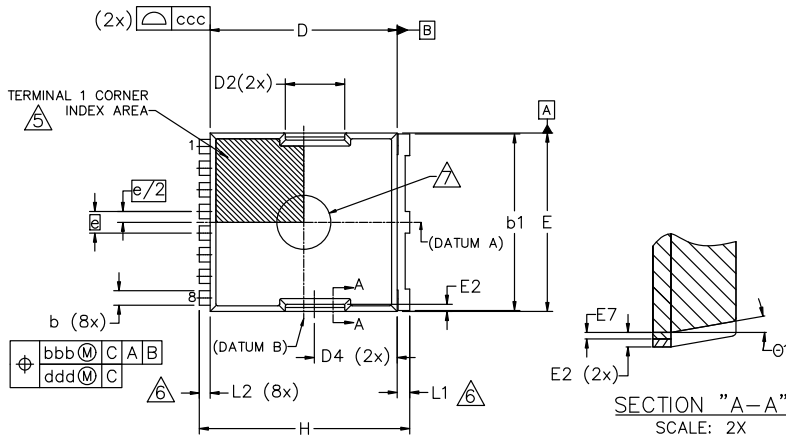
Revision	Description of Changes	Date
4	Rebranded the document to onsemi format.	3/27/2026

This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.

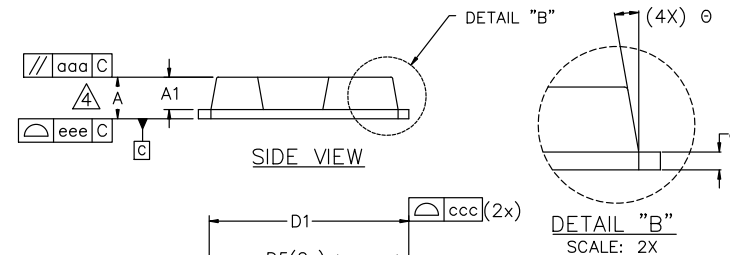



H-PSOF8L 10.38x9.90x2.30, 1.20P
CASE 100CU
ISSUE G

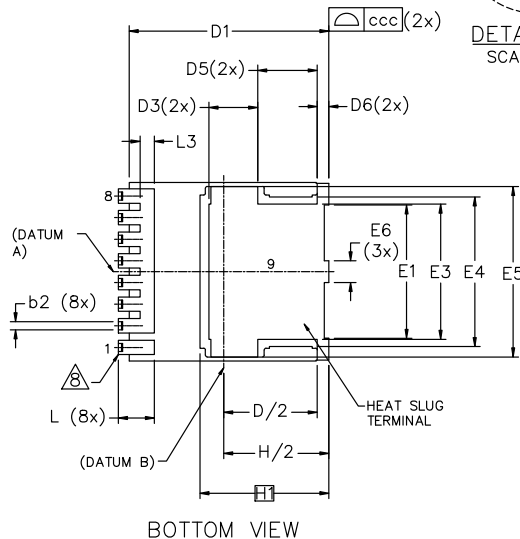
DATE 24 AUG 2026



*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE onsemi SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERM/D.



- NOTES:
1. PACKAGE STANDARD REFERENCE: JEDEC MO-299, ISSUE B.
 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
 3. "e" REPRESENTS THE TERMINAL PITCH.
 4. COPLANARITY APPLIES TO EXPOSED PAD AND LEADS..
 5. A VISUAL INDEX FEATURE MUST BE LOCATED WITHIN THE HATCHED AREA.
 6. DIMENSIONS b1,L1,L2 APPLY TO PLATED TERMINALS.
 7. THE LOCATION AND SIZE OF EJECTOR MARKS ARE OPTIONAL.
 8. THE LOCATION AND NUMBER OF FUSED LEADS ARE OPTIONAL.

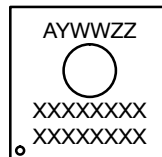


DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	2.20	2.30	2.40
A1	1.70	1.80	1.90
b	0.70	0.80	0.90
b1	9.70	9.80	9.90
b2	0.35	0.45	0.55
c	0.40	0.50	0.60
D	10.28	10.38	10.48
D/2	5.09	5.19	5.29
D1	10.98	11.08	11.18
D2	3.20	3.30	3.40
D3	2.60	2.70	2.80
D4	4.45	4.55	4.65
D5	3.20	3.30	3.40
D6	0.55	0.65	0.75
E	9.80	9.90	10.00
E1	7.30	7.40	7.50
E2	0.30	0.40	0.50
E3	7.40	7.50	7.60
E4	8.20	8.30	8.40

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
E5	9.36	9.46	9.56
E6	1.10	1.20	1.30
E7	0.15	0.18	0.21
e	1.20 BSC		
e/2	0.60 BSC		
H	11.58	11.68	11.78
H/2	5.74	5.84	5.94
H1	7.15 BSC		
L	1.90	2.00	2.10
L1	0.60	0.70	0.80
L2	0.50	0.60	0.70
L3	0.70	0.80	0.90
theta	10° REF		
theta1	10° REF		
aaa	0.20		
bbb	0.25		
ccc	0.20		
ddd	0.20		
eee	0.10		

GENERIC MARKING DIAGRAM*

A = Assembly Location
Y = Year
WW = Work Week
ZZ = Assembly Lot Code
XXXX = Specific Device Code



*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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